NSN 5961-01-221-8224

Transistor - Page 1 of 1

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-221-8224

Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

Between 0.250 inches and 0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1200.0 collector-to-emitter, with voltage between base and emitter and 800.0 collector-to-emitter, substaining voltage, base open-circuited and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

5.00 amperes source cutoff current and 2.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

19623-006274 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0